NJM2863/64

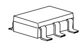
Ultra Low Noise Low Dropout Voltage Regulator

■ GENERAL DESCRIPTION

The NJM2863/64 is a 2ch low dropout voltage regulator designed for VCO Applications.

Advanced Bipolar technology achieves low noise, high ripple rejection and low quiescent current.

■ PACKAGE OUTLINE

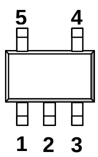


NJM2863F/64F

■ FEATURES

- High Ripple Rejection 75dB typ. (f=1kHz)
- Output capacitor with 1.0µF ceramic capacitor
- Output Noise Voltage Vno=19µVrms typ. (Cp=0.01µF, Co=1.0µF(Ceramic))
  Vno=12µVrms typ. (Cp=0.1µF, Co=10µF(Tantalum))
- Output Current Io(max.)=100mA
- High Precision Output Vo±1.0%
- Low Dropout Voltage 0.10V typ. (Io=60mA)
- ON/OFF Control (Active High)
- Internal Short Circuit Current Limit
- Internal Thermal Overload Protection
- Bipolar Technology
- Package Outline MTP5

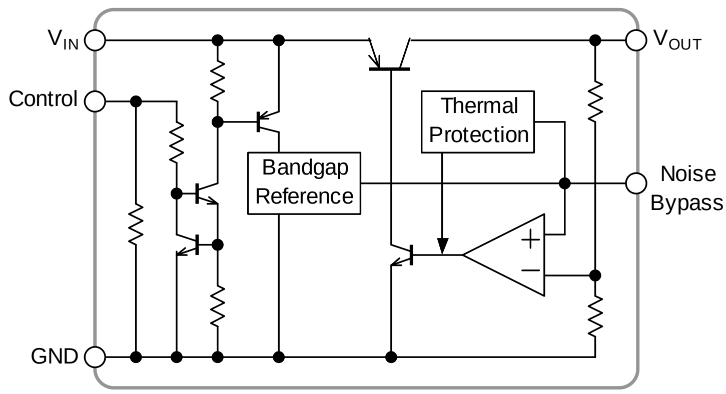
■ PIN CONFIGURATION



PIN FUNCTION

NJM2863F	NJM2864F
1.CONTROL	1.V_{IN}
2.GND	2.GND
3.NOISE BYPASS	3.CONTROL
4.V_{OUT}	4.NOISE BYPASS
5.V_{IN}	5.V_{OUT}

■ EQUIVALENT CIRCUIT



■ OUTPUT VOLTAGE RANK LIST

Device Name	V_{OUT}	Device Name	V_{OUT}
NJM286×F21	2.1V	NJM286×F29	2.9V
NJM286×F25	2.5V	NJM286×F03	3.0V
NJM286×F27	2.7V	NJM286×F33	3.3V
NJM286×F28	2.8V	NJM286×F05	5.0V
NJM286×F285	2.85V		

■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Input Voltage	V_{IN}	+14	V
Control Voltage	V_{CONT}	+14(*note 1)	V
Power Dissipation	P_D	200	mW
Operating Temperature	Topr	–40 ~ +85	°C
Storage Temperature	Tstg	–40 ~ +125	°C

(*note 1): When input voltage is less than +14V, the absolute maximum control voltage is equal to the input voltage.

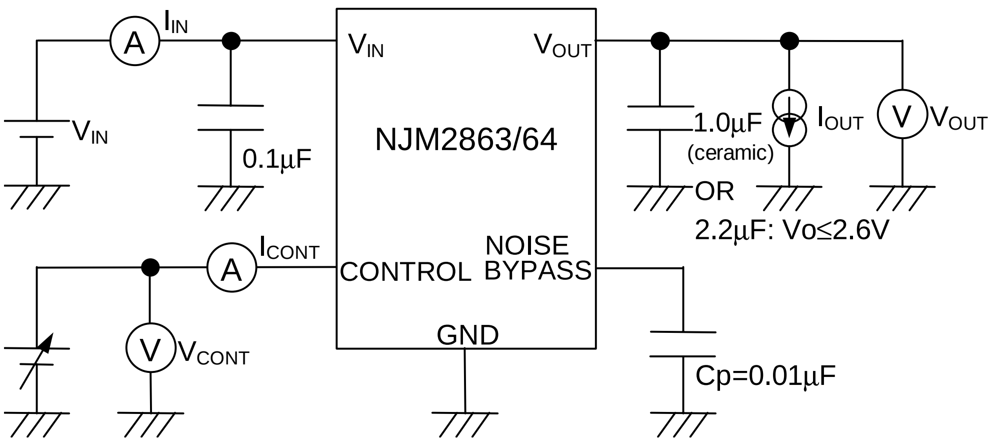
■ ELECTRICAL CHARACTERISTICS

(V_{IN}=Vo+1V, C_{IN}=0.1µF, Co=1.0µF: Vo≥2.7V (Co=2.2µF: Vo≤2.6V), Cp=0.01µF, Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Voltage	Vo	Io=30mA	-1.0%	–	+1.0%	V
Quiescent Current	I_Q	Io=0mA, except Icont	–	120	180	µA
Quiescent Current at Control OFF	$I_{Q(OFF)}$	V_{CONT}=0V	–	–	100	nA
Output Current	Io	Vo-0.3V	100	130	–	mA
Line Regulation	$\Delta Vo/\Delta V_{IN}$	V_{IN}=Vo+1V ~ Vo+6V, Io=30mA	–	–	0.10	%/V
Load Regulation	ΔVo/ΔIo	Io=0 ~ 100mA	–	–	0.03	%/mA
Dropout Voltage	ΔV_{I-O}	Io=60mA	–	0.10	0.18	V
Ripple Rejection	RR	ein=200mVrms,f=1kHz, Io=10mA, Vo=3V Version	–	75	–	dB
Average Temperature Coefficient of Output Voltage	ΔVo/ΔTa	Ta=0~85°C, Io=10mA	–	±50	–	ppm/°C
Output Noise Voltage1	V_{NO1}	f=10Hz~80kHz, Io=10mA, Cp=0.01µF, Co=1.0µF (Ceramic), Vo=3V Version	–	19	–	µVrms
Output Noise Voltage2	V_{NO2}	f=10Hz~80kHz, Io=10mA, Cp=0.1µF, Co=10µF (Tantalum), Vo=3V Version		12		µVrms
Control Voltage for ON-state	$V_{CONT(ON)}$		1.6	–	–	V
Control Voltage for OFF-state	$V_{CONT(OFF)}$		–	–	0.6	V

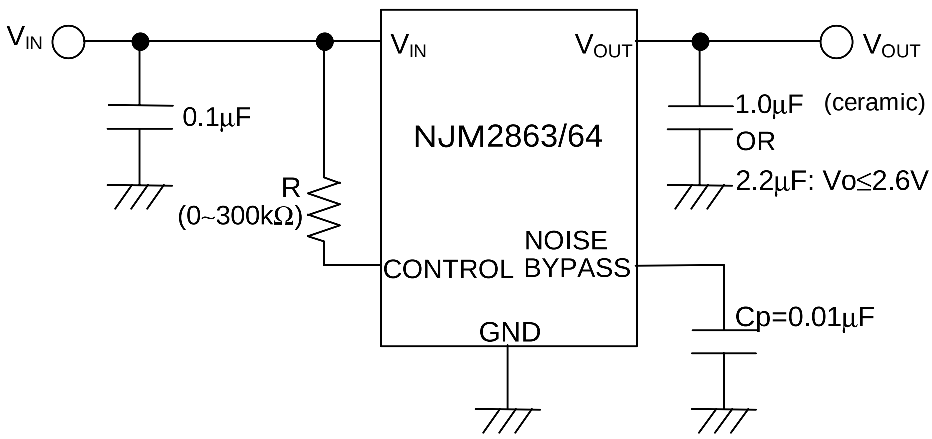
(*note 2): The above specification is a common specification for all output voltages.
Therefore, it may be different from the individual specification for a specific output voltage.

■ TEST CIRCUIT



■ TYPICAL APPLICATION

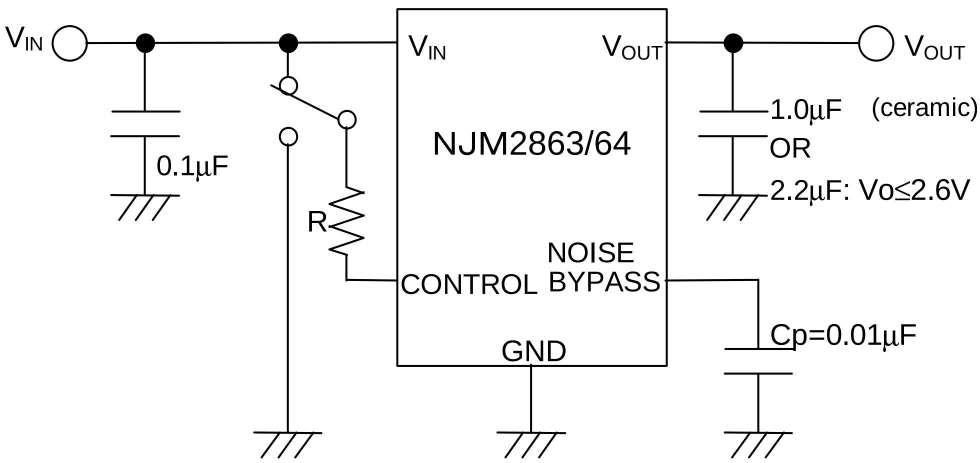
① In the case where ON/OFF Control is not required:



Connect control terminal to V_{IN} terminal

The quiescent current can be reduced by using a resistance "R". Instead, it increases the minimum operating voltage. For further information, please refer to Figure "Output Voltage vs. Control Voltage".

② In use of ON/OFF CONTROL:



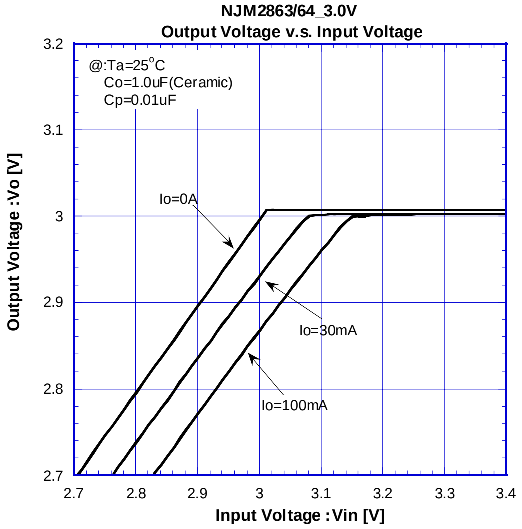
State of control terminal:

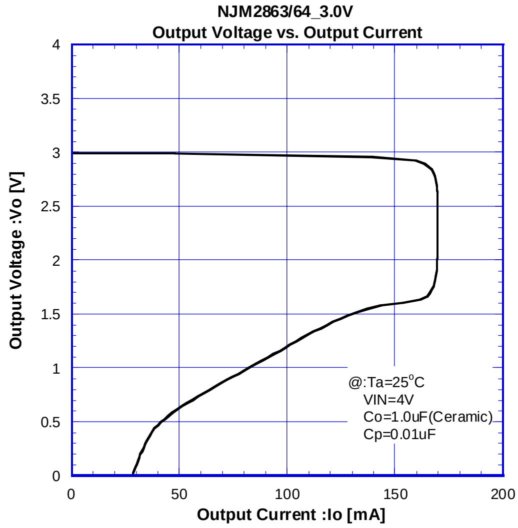
- "H"→ output is enabled.
- "L" or "open" → output is disabled.

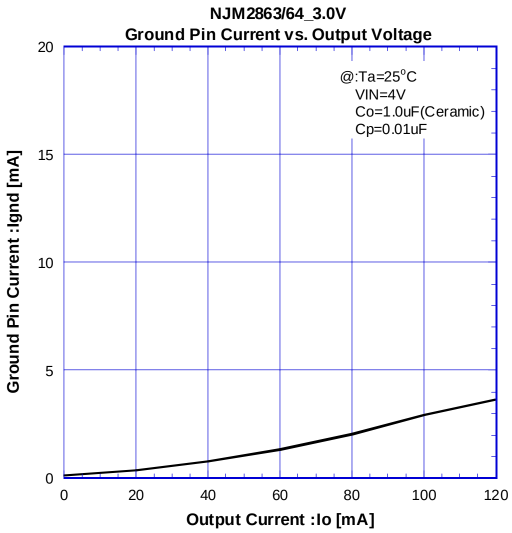
∗Noise bypass Capacitance Cp

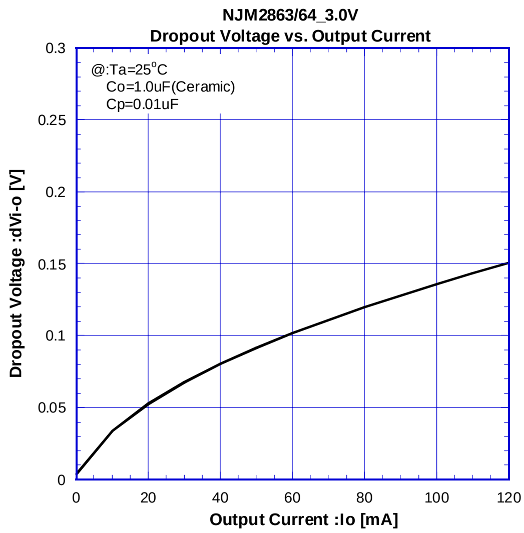
Noise bypass capacitance Cp reduces noise generated by band-gap reference circuit.
Noise level and ripple rejection will be improved when larger Cp is used.
Use of smaller Cp value may cause oscillation.
Use the Cp value of 0.01µF greater to avoid the problem.

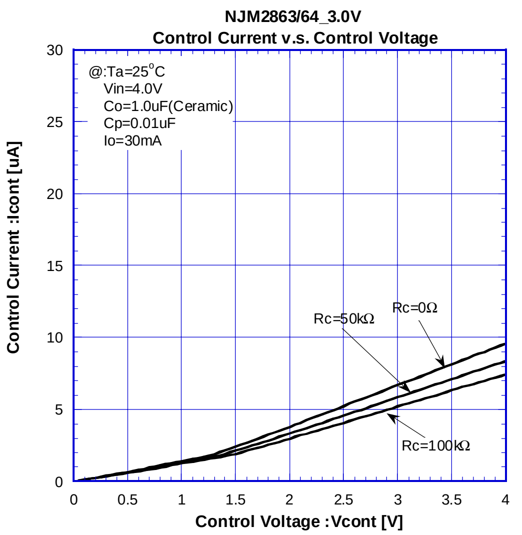
■ ELECTRICAL CHARACTERISTICS

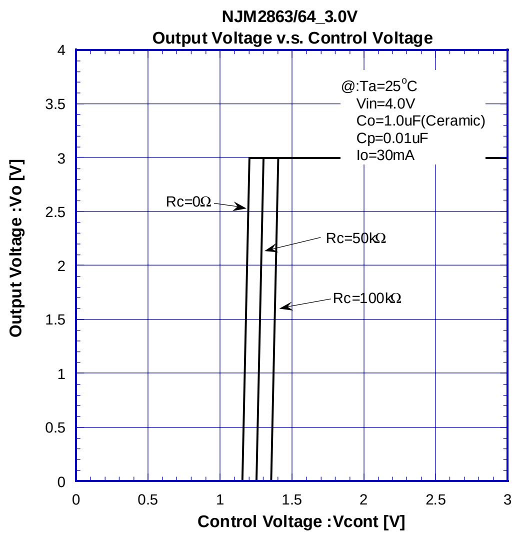




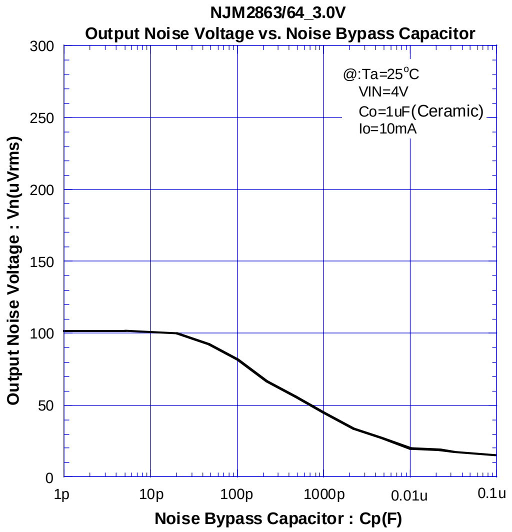


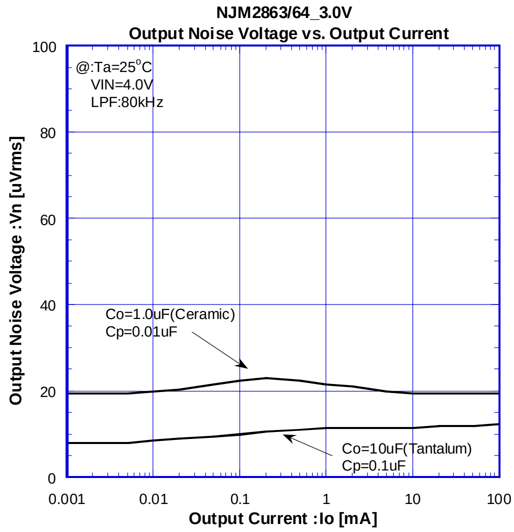


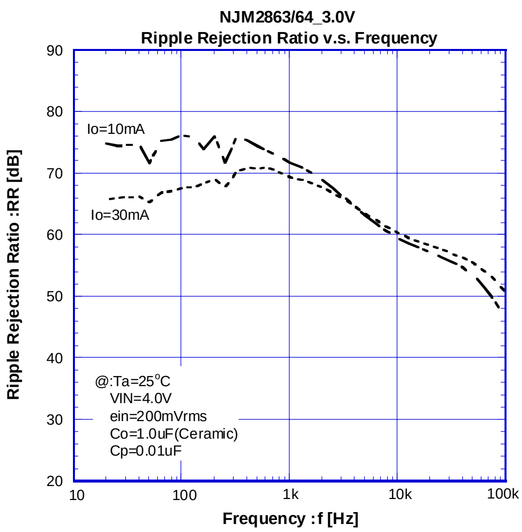


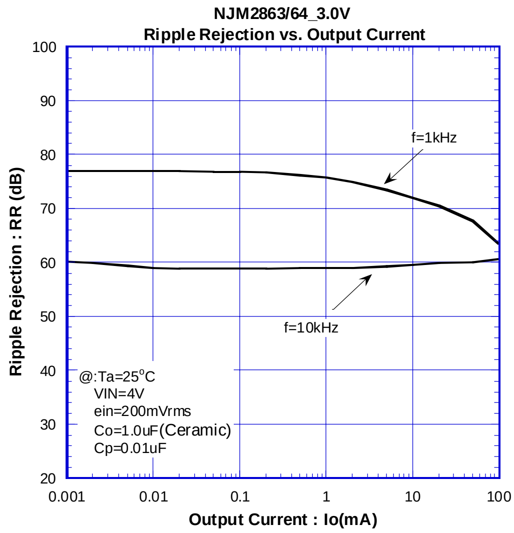


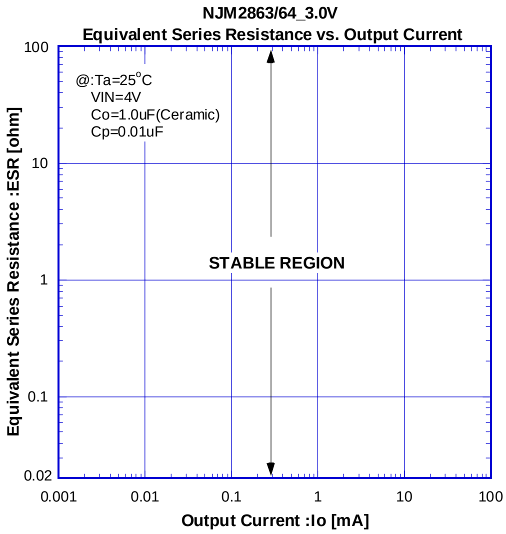
■ ELECTRICAL CHARACTERISTICS











■ ELECTRICAL CHARACTERISTICS